## **CLAIMS**

1. A process for cleaning a reactor wherein the reactor is used to coat TiO<sub>2</sub> onto an article, said process comprising:

providing the reactor to be cleaned wherein the reactor contains a chamber comprising a surface at least partially coated with a substance comprising TiO<sub>2</sub>;

adding to the reactor a reactive gas comprising at least one cleaning agent;

reacting the substance with the reactive gas to form at least one volatile product; and

removing from the reactor the at least one volatile product to clean the reactor.

- 2. The process of claim 1, wherein the at least one cleaning gas is selected from a fluorine-containing cleaning gas, a chlorine-containing cleaning gas, and combinations thereof.
- 3. The process of claim 2, wherein the at least one cleaning gas is a chlorine-containing cleaning gas.
- 4. The process of claim 3 wherein the chlorine-containing cleaning gas is at least one member selected from the group consisting of  $BCl_3$ ,  $COCl_2$ , HCl,  $Cl_2$ ,  $CIF_3$ , and  $NF_zCl_{3-z}$ , where z is an integer from 0 to 2.
- 5. The process of claim 2 wherein the at least one cleaning gas is a fluorine-containing cleaning gas.
- 6. The process of claim 5 wherein the fluorine-containing cleaning gas comprises at least one member selected from NF<sub>3</sub>; CIF<sub>3</sub>; CIF; SF<sub>6</sub>; a perfluorocarbon; a hydrofluorocarbon; an oxyfluorocarbon; a hypofluorite, a fluoroperoxide; a fluorotrioxide; COF<sub>2</sub>; NOF; F<sub>2</sub>; NF<sub>n</sub>Cl<sub>3-n</sub>, where n is a number ranging from 1 to 2; and combinations thereof.
- 7. The process of claim 6, wherein the fluorine-containing cleaning gas is NF<sub>3</sub>.
- 8. The process of claim 1, wherein the reactive gas further comprises an inert diluent gas.

- 9. The process of claim 1, wherein the reacting step is conducted by an in situ plasma, a remote plasma, an in-situ thermal source, a remote thermal source, a remote catalytic source, a photon activation source, and combinations thereof.
- 10. The process of claim 9, wherein the reacting step is conducted by an in situ plasma.
- 11. The process of claim 9 wherein the reacting step is conducted by a remote plasma.
- 12. The process of claim 1, wherein the reactive gas is conveyed to the chamber from a gas cylinder, a safe delivery system, a pipeline, a point of use delivery system, a vacuum delivery system, and combinations thereof.
- 13. The process of claim 1, wherein the fluorine-containing reactive gas is formed in close proximity to the reactor by a point-of-use generator.
- 14. The process of claim 1 wherein the article is selected from a glass-containing work piece, a metal-containing work piece, a ceramic work piece, and mixtures thereof.
- 15. A process for the deposition of a TiO<sub>2</sub> coating on a glass article, the process comprising:

placing the glass article into a reactor;

depositing the TiO<sub>2</sub> coating onto the glass article and a substance comprising TiO<sub>2</sub> onto at least one surface within the reactor using at least one metal precursor wherein the depositing step is conducted by a process selected from chemical vapor deposition, vacuum deposition, spray pyrolysis and combinations thereof;

adding to the reactor a reactive gas comprising at least one cleaning agent; reacting the substance with the reactive gas to form at least one volatile product; and

removing from the reactor the at least one volatile product to clean the reactor.